

**SILVER OAK COLLEGE OF ENGINEERING & TECHNOLOGY****BE - SEMESTER-I • MID SEMESTER-I EXAMINATION – WINTER 2018****SUBJECT: BASIC ELECTRONICS (3110016) (IT)**

DATE: 09-10-2018

TIME: 02:00 pm to 3:30 pm

TOTAL MARKS:40

- Instructions:** 1.Q. 1 is compulsory.  
 2. Figures to the right indicate full marks.  
 3. Assume suitable data if required.

- Q.1 (a) Give Answer with most suitable/correct option. [05]
- (i) An ideal diode has forward resistance of \_\_\_\_\_.  
 (a) 10 ohm (b) 0 ohm (c) 100K ohm (d) 1M ohm
- (ii) \_\_\_\_\_ region of transistor is most heavily doped.  
 (a) Emitter (b) Collector (c) Base (d) Both Emitter and Collector
- (iii) The Peak Inverse Voltage of Bridge rectifier is \_\_\_\_\_.  
 (a)  $V_m$  (b)  $2V_m$  (c) 0 (d) Infinite
- (iv) The cut-in voltage of Silicon p-n junction diode is \_\_\_\_\_ V.  
 (a) 0 (b) 1 (c) 0.7 (d) 0.3
- (v) Transistor works as an amplifier if it operates in \_\_\_\_\_ region.  
 (a) Cutoff (b) Saturation (c) Active (d) Inverse
- (b) Explain the formation of barrier potential in open circuited PN junction diode. [05]

- Q.2 (a) Explain operation of PN junction diode in forward biased and reverse biased condition with the help of V-I characteristics. [06]
- (b) Draw neat circuit diagram of Full wave center tapped rectifier and explain its operation with the help of waveforms. [05]
- (c) Show that NAND gate is Universal gate. [04]

**OR**

- Q.2 (a) Draw neat circuit diagram of Full wave Bridge rectifier and explain its operation with the help of waveforms. [06]
- (b) Differentiate Avalanche breakdown and Zener breakdown phenomenon in p-n junction diode. [05]
- (c) Construct all logic gates with the help of NOR gate. [04]

- Q.3 (a) A sinusoidal voltage of peak value of 40 V and frequency 50 Hz is applied at the input of a half wave rectifier, No filter is used. The load resistance is 500  $\Omega$ . Diode has  $R_f = 5 \Omega$ ,  $R_r = \infty$ . Calculate: (i) DC value, rms value of load current and load voltage, (ii) Rectification Efficiency. [06]
- (b) Explain the operation of npn transistor with the help of various current components in transistor. Draw necessary diagram. Also, consider that transistor is biased in active region. [05]
- (c) With the help of circuit diagram, explain the operation of positive clamper circuit. [04]

**OR**

- Q.3 (a) Explain the construction of transistor and also mention its regions of operation. [06]
- (b) Discuss the working of series positive and negative clipper circuits with the help of input-output waveforms. [05]
- (c) Draw three approximations of a diode. [04]

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